NPN Triple Diffused Planar Silicon Transistor



2SC4425

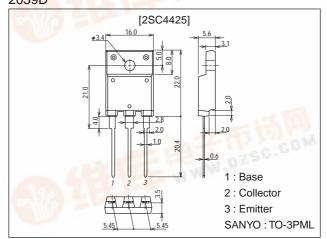
400V/25A Switching Regulator Applications

Features

- · High breakdown voltage, high reliability.
- · Fast switching speed (t_f : 0.1 μ s typ).
- · Wide ASO.
- · Adoption of MBIT process.
- · Micaless package facilitating easy mounting.

Package Dimensions

unit:mm 2039D



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		500	V
Collector-to-Emitter Voltage	V _{CEO}		400	V
Emitter-to-Base Voltage	V _{EBO}	140	7	V
Collector Current	IC	- 4	25	А
Collector Current (Pulse)	I _{CP}	PW≤300μs, duty cycle≤10%	40	Α
Base Current	Ι _Β	AND ASSESSMENT WAS	8	Α
Collector Dissipation	PC	199	3	W
		Tc=25°C	65	W
Junction Temperature	Tj	D and	150	°C
Storage Temperature	Tstg	- Co.	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =400V, I _E =0			10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	μA
DC Current Gain	h _{FE} 1*	V _{CE} =5V, I _C =3.2A	15	L 07	50	
	h _{FE} 2	V _{CE} =5V, I _C =16A	10			
	h _{FE} 3	V _{CE} =5V, I _C =10mA	10			

^{*:} The h_{FE}1 of the 2SC4425 is classified as follows. When specifying the h_{FE}1 rank, specify two ranks or more in principle.

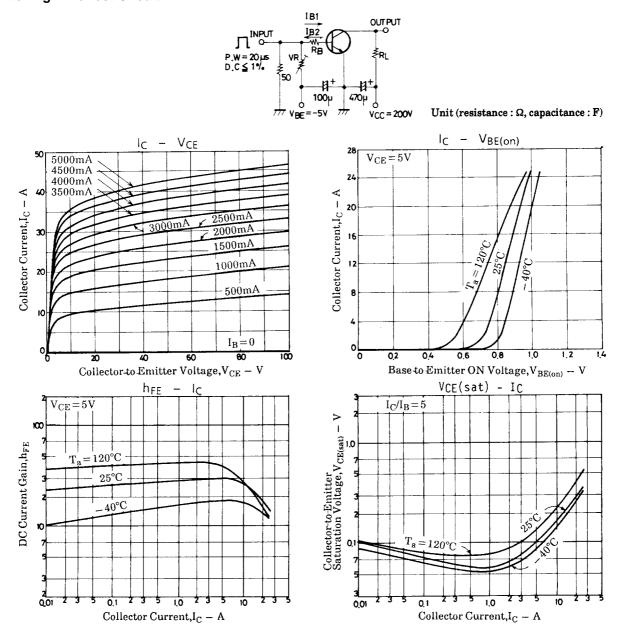
15 L 30 20 M 40 30 N 50

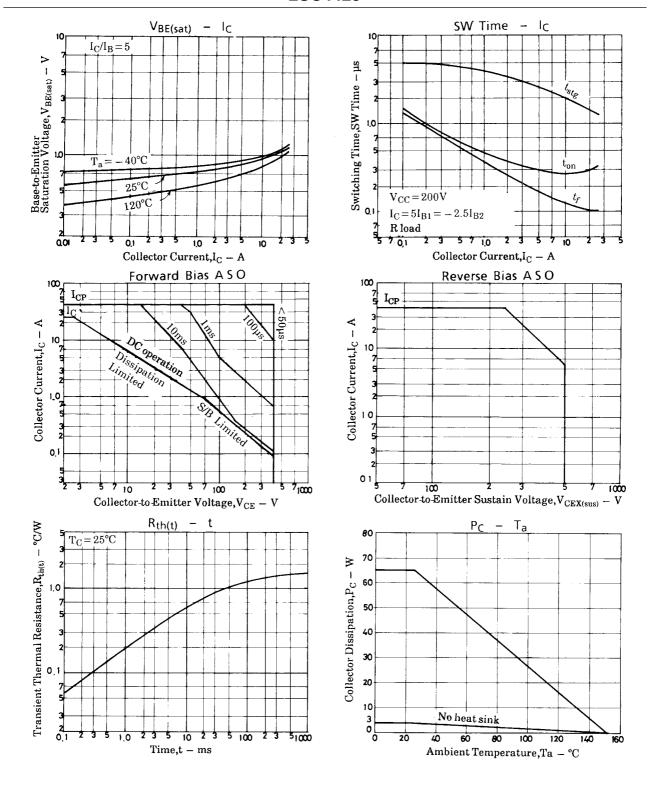
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =16A, I _B =3.2A			0.8	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =16A, I _B =3.2A			1.5	V
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =3.2A		20		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		300		pF
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =10mA, R _{BE} =∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =10A, I _{B1} =1A, I _{B2} =-4A, L=200μH, Clamped	400			V
Turn-ON Time	ton	I _C =20A, I _{B1} =4A, I _{B2} =-8A, R _L =10Ω, V _{CC} =200V			0.5	μs
Storage Time	t _{stg}	I _C =20A, I _{B1} =4A, I _{B2} =-8A, R _L =10Ω, V _{CC} =200V			2.5	μs
Fall Time	t _f	I _C =20A, I _{B1} =4A, I _{B2} =-8A, R _L =10Ω, V _{CC} =200V			0.3	μs

Switching Time Test Circuit





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